# 2.5/3.3V Differential LVPECL 1:9 Clock Distribution Buffer and Clock Divider

The Motorola MC100ES6226 is a bipolar monolithic differential clock distribution buffer and clock divider. Designed for most demanding clock distribution systems, the MC100ES6226 supports various applications that require a large number of outputs to drive precisely aligned clock signals. Using SiGe technology and a fully differential architecture, the device offers superior digitial signal characteristics and very low clock skew error. Target applications for this clock driver are high performance clock distribution systems for computing, networking and telecommunication systems.

### Features:

- Fully differential architecture from input to all outputs
- · SiGe technology supports near-zero output skew
- Selectable 1:1 or 1:2 frequency outputs
- LVPECL compatible differential clock inputs and outputs
- LVCMOS compatible control inputs
- Single 3.3V or 2.5V supply
- Max. 35 ps maximum output skew (within output bank)
- Max. 50 ps maximum device skew
- Supports DC operation and up to 3 GHz (typ.) clock signals
- Synchronous output enable eliminating output runt pulse generation and metastability
- Standard 32 lead LQFP package
- Industrial temperature range

### **Functional Description**

MC100ES6226 is designed for very skew critical differential clock distribution systems and supports clock frequencies from DC up to 3.0 GHz. Typical applications for the MC100ES6226 are primary clock distribution systems on backplanes of high-performance computer, networking and telecommunication systems, as well as on-board clocking of OC-3, OC-12 and OC-48 speed communication systems.

The MC100ES6226 can be operated from a 3.3V or 2.5V positive supply without the requirement of a negative supply line. Each of the output banks of three differential clock output pairs may be independently configured to distribute the input frequency or half of the input frequency. The FSEL0 and FSEL1 clock frequency selects are asychronous control inputs. Any changes of the control inputs require a MR pulse for resynchronization of the ÷2 outputs.

## MC100ES6226

2.5V/3.3V DIFFERENTIAL LVPECL 1:9 CLOCK **DISTRIBUTION BUFFER AND CLOCK DIVIDER** 



**FA SUFFIX** 32-LEAD LQFP PACKAGE CASE 873A



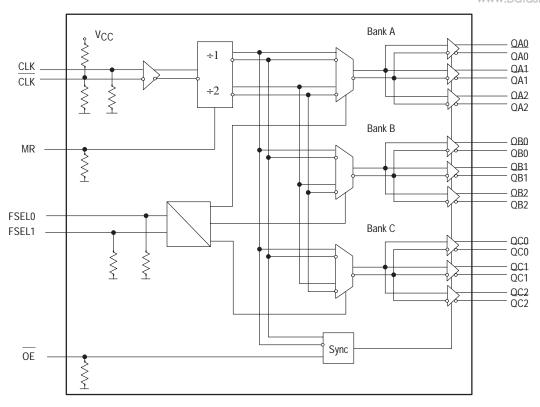


Figure 1. MC100ES6226 Logic Diagram

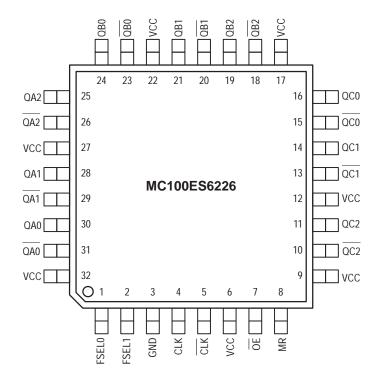


Figure 2. 32-Lead Package Pinout (Top View)

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### **TABLE 1: PIN CONFIGURATION**

Pin	I/O	Туре	Function
CLK, CLK	Input	LVPECL	Differential reference clock signal input
OE	Input	LVCMOS	Output enable
MR	Input	LVCMOS	Device reset
FSEL0, FSEL1	Input	LVCMOS	Output frequency divider select
QA[0-2], QA[0-2] QB[0-2], QB[0-2] QC[0-2], QC[0-2]	Output	LVPECL	Differential clock outputs (banks A, B and C)
GND	Supply	GND	Negative power supply
VCC	Supply	VCC	Positive power supply. All V <sub>CC</sub> pins must be connected to the positive power supply for correct DC and AC operation

### **TABLE 2: FUNCTION TABLE**

Control	Default	0	1
ŌĒ	0	Qx[0-2], Qx[0-2] are active. Deassertion of OE can be asynchronous to the reference clock without generation of output runt pulses	Qx[0-2] = L, Qx[0-2] =H (outputs disabled).  Assertion of OE can be asynchronous to the reference clock without generation of output runt pulses
MR	0	Normal operation	Device reset (asynchronous)
FSEL0, FSEL1	00	See Following Table	

### **TABLE 3: Output Frequency Select Control**

FSEL0	FSEL1	QA0 to QA2	QB0 to QB2	QC0 to QC2
0	0	fQA0:2 = fCLK	fQB0:2 = fCLK	fQC0:2 = fCLK
0	1	fQA0:2 = fCLK	fQB0:2 = fCLK	$f_{QC0:2} = f_{CLK} \div 2$
1	0	f <sub>QA0:2</sub> = f <sub>CLK</sub>	f <sub>QB0:2</sub> = f <sub>CLK</sub> ÷ 2	$f_{QC0:2} = f_{CLK} \div 2$
1	1	$f_{QA0:2} = f_{CLK} \div 2$	f <sub>QB0:2</sub> = f <sub>CLK</sub> ÷ 2	$f_{QC0:2} = f_{CLK} \div 2$

### **TABLE 4: ABSOLUTE MAXIMUM RATINGS**<sup>a</sup>

Symbol	Characteristics	Min	Max	Unit	Condition
Vcc	Supply Voltage	-0.3	3.6	V	
VIN	DC Input Voltage	-0.3	V <sub>CC</sub> +0.3	V	
Vout	DC Output Voltage	-0.3	V <sub>CC</sub> +0.3	V	
IIN	DC Input Current		±20	mA	
lout	DC Output Current		±50	mA	
TS	Storage temperature	-65	125	°C	

a. Absolute maximum continuous ratings are those maximum values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation at absolute-maximum-rated conditions is not implied.

### **TABLE 5: GENERAL SPECIFICATIONS**

Symbol	Characteristics	Min	Тур	Max	Unit	Condition
VTT	Output termination voltage		Vcc - 2 <sup>a</sup>		V	
MM	ESD Protection (Machine model)	200			V	
HBM	ESD Protection (Human body model)	2000			V	
CDM	ESD Protection (Charged device model)	1000			V	
LU	Latch-up immunity	200			mA	
C <sub>IN</sub>			4.0		pF	Inputs
θЈΑ	Thermal resistance junction to ambient JESD 51-3, single layer test board  JESD 51-6, 2S2P multilayer test board		83.1 73.3 68.9 63.8 57.4 59.0 54.4 52.5 50.4 47.8	86.0 75.4 70.9 65.3 59.6 60.6 55.7 53.8 51.5 48.8	°C/W °C/W °C/W °C/W °C/W °C/W °C/W °C/W	Natural convection 100 ft/min 200 ft/min 400 ft/min 800 ft/min  Natural convection 100 ft/min 200 ft/min 400 ft/min 800 ft/min
θЈС	Thermal resistance junction to case		23.0	26.3	°C/W	MIL-SPEC 883E Method 1012.1
	Operating junction temperatureb (continuous operation) MTBF = 9.1 years	0		110	°C	

a. Output termination voltage V<sub>TT</sub> = 0V for V<sub>CC</sub> = 2.5V operation is supported but the power consumption of the device will increase.

b. Operating junction temperature impacts device life time. Maximum continuous operating junction temperature should be selected according to the application life time requirements (See application note AN1545 for more information). The device AC and DC parameters are specified up to 110°C junction temperature allowing the MC100ES6226 to be used in applications requiring industrial temperature range. It is recommended that users of the MC100ES6226 employ thermal modeling analysis to assist in applying the junction temperature specifications to their particular application.

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TABLE 6: DC CHARACTERISTICS ( $V_{CC}$  = 3.3V  $\pm$  5% and 2.5V  $\pm$  5%,  $T_J$  = 0°C to +110°C)<sup>a</sup>

Symbol	Characteristics	Min	Тур	Max	Unit	Condition	
LVCMOS	LVCMOS control inputs (OE, FSEL0, FSEL1, MR)						
V <sub>IL</sub>	Input voltage low $V_{CC} = 3.3 \text{ V}$ $V_{CC} = 2.5 \text{ V}$			0.8 0.7	V		
VIH	Input voltage high $V_{CC} = 3.3 \text{ V}$ $V_{CC} = 2.5 \text{ V}$	2.2 1.7			V		
I <sub>IN</sub>	Input Current <sup>b</sup>			±150	μΑ	$V_{IN} = V_{CC}$ or $V_{IN} = GND$	
LVPECL	clock inputs (CLK, CLK) <sup>C</sup>						
V <sub>PP</sub>	DC differential input voltaged	0.1		1.3	V	Differential operation	
VCMR	Differential cross point voltage <sup>e</sup>	1.0		V <sub>CC</sub> -0.3	V	Differential operation	
VIH	Input high voltage	TBD		TBD			
VIL	Input low voltage	TBD		TBD			
I <sub>IN</sub>	Input Current			±150	μΑ	$V_{IN} = TBD \text{ or } V_{IN} = TBD$	
LVPECL	. clock outputs (QA[2:0], QB[2:0], QC[2:0	])					
Vон	Output High Voltage	V <sub>CC</sub> -1.1		V <sub>CC</sub> -0.8	V	Termination 50Ω to V <sub>TT</sub>	
VOL	Output Low Voltage	V <sub>CC</sub> -1.8		V <sub>CC</sub> -1.4	V	Termination 50Ω to V <sub>TT</sub>	
Supply o	Supply current						
IGND	Maximum Quiescent Supply Current without output termination current		65	110	mA	GND pin	
ICC	Maximum Quiescent Supply Current with output termination current		325	400	mA	All V <sub>CC</sub> Pins	

- a. AC characterisitics are design targets and pending characterization.
- b. Input have internal pullup/pulldown resistors which affect the input current.
- c. Clock inputs driven by LVPECL compatible signals.
- d. VPP is the minimum differential input voltage swing required to maintain AC characteristic.
- e. V<sub>CMR</sub> (DC) is the crosspoint of the differential input signal. Functional operation is obtained when the crosspoint is within the V<sub>CMR</sub> (DC) range and the input swing lies within the V<sub>PP</sub> (DC) specification.

TABLE 7: AC CHARACTERISTICS ( $V_{CC} = 3.3V \pm 5\%$  and  $2.5V \pm 5\%$ ,  $T_J = 0^{\circ}C$  to  $+110^{\circ}C$ )a b

Symbol	Characteristics	Min	Тур	Max	Unit	Condition
VPP	Differential input voltage <sup>C</sup> (peak-to-peak)	0.2	0.3	1.3	V	
VCMR	Differential input crosspoint voltage <sup>d</sup>	1.0		V <sub>CC</sub> -0.3	V	
V <sub>X</sub> ,OUT	Differential output crosspoint voltage	V <sub>CC</sub> -1.45		V <sub>CC</sub> -1.1	V	
V <sub>O(P-P)</sub>	Differential output voltage (peak-to-peak)					
, ,	f <sub>O</sub> < 300 MHz	0.45	0.72	0.95	V	
	f <sub>O</sub> < 1.5 GHz		0.55	0.95	V	
	f <sub>O</sub> < 2.7 GHz		0.37	0.95		
fCLK	Input Frequency	0		3000e	MHz	
tPD	Propagation Delay CLK to Qx[]	475	500	800	ps	Differential
tsk(O)	Output-to-output skew (within QA[2:0])		11	25	ps	Differential
, ,	(within QB[2:0])		12	25	ps	
	(within QC[2:0])		4	20	ps	
	(within device)			60	ps	
tsk(PP)	Output-to-output skew (part-to-part)			325	ps	Differential
tJIT(CC)	Output cycle-to-cycle jitter					
	single frequency configuration			TBD		FSEL0 = FSEL1
	÷1/÷2 frequency configuration			TBD		FSEL0≠FSEL1
DCO	Output duty cycle $Qx = \pm 1$ , $f_O < 300 \text{ MHz}$	48	50	52	%	DC <sub>fref</sub> = 50%
	$Qx = \div 1$ , $f_O > 300 MHz$	45	50	55	%	
	Ov 2 f 200 MH=	49	50	51	%	
	$Qx = \div 2, f_O < 300 \text{ MHz}$ $Qx = \div 2, f_O > 300 \text{ MHz}$	49	50	52.5	% %	
4.4.			30			200/ += 000/
t <sub>r</sub> , t <sub>f</sub>	Output Rise/Fall Time	0.05		200	ns	20% to 80%
t <sub>PDL</sub> t	Output disable time	2.5·T + tpD		4.5·T + tpD	ns	T=CLK period
t <sub>PLD</sub> g	Output enable time	3-T + tpD		5·T + tpD	ns	T=CLK period

- a. AC characterisitics are design targets and pending characterization.
- b. AC characteristics apply for parallel output termination of  $50\Omega$  to V<sub>TT</sub>.
- c. Vpp is the minimum differential input voltage swing required to maintain AC characteristics including tpd and device-to-device skew.
- d. V<sub>CMR</sub> (AC) is the crosspoint of the differential input signal. Normal AC operation is obtained when the crosspoint is within the V<sub>CMR</sub> (AC) range and the input swing lies within the V<sub>PP</sub> (AC) specification. Violation of V<sub>CMR</sub> (AC) or V<sub>PP</sub> (AC) impacts the device propagation delay, device and part-to-part skew.
- e. The MC100ES6226 is fully operational up to 3.0 GHz and is characterized up to 2.7 GHz.
- f. Propagation delay OE deassertion to differential output disabled (differential low: true output low, complementary output high).
- g. Propagation delay OE assertion to output enabled (active).

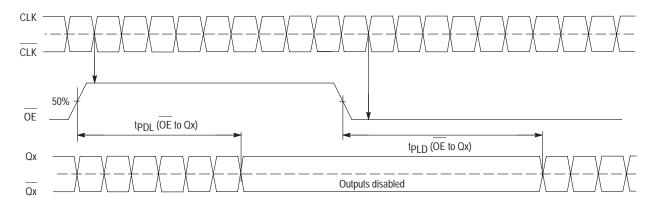


Figure 3. MC100ES6226 output disable/enable timing

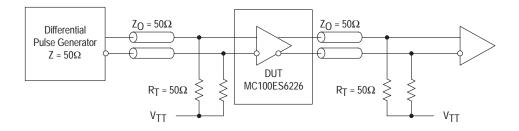


Figure 4. MC100ES6226 AC test reference

### APPLICATIONS INFORMATION

### **Maintaining Lowest Device Skew**

The MC100ES6226 guarantees low output-to-output bank skew of 35 ps and a part-to-part skew of max. TBD ps. To ensure low skew clock signals in the application, both outputs of any differential output pair need to be terminated identically, even if only one output is used. When fewer than all nine output pairs are used, identical termination of all output pairs within the output bank is recommended. If an entire output bank is not used, it is recommended to leave all of these outputs open and unterminated. This will reduce the device power consumption while maintaining minimum output skew.

### **Power Supply Bypassing**

The MC100ES6226 is a mixed analog/digital product. The differential architecture of the MC100ES6226 supports low noise signal operation at high frequencies. In order to maintain its superior signal quality, all V<sub>CC</sub> pins should be bypassed by high-frequency ceramic capacitors connected

to GND. If the spectral frequencies of the internally generated switching noise on the supply pins cross the series resonant point of an individual bypass capacitor, its overall impedance begins to look inductive and thus increases with increasing frequency. The parallel capacitor combination shown ensures that a low impedance path to ground exists for frequencies well above the noise bandwidth.

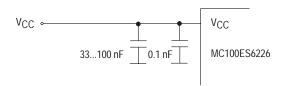


Figure 5. VCC Power Supply Bypass

# **NOTES**

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**NOTES** 

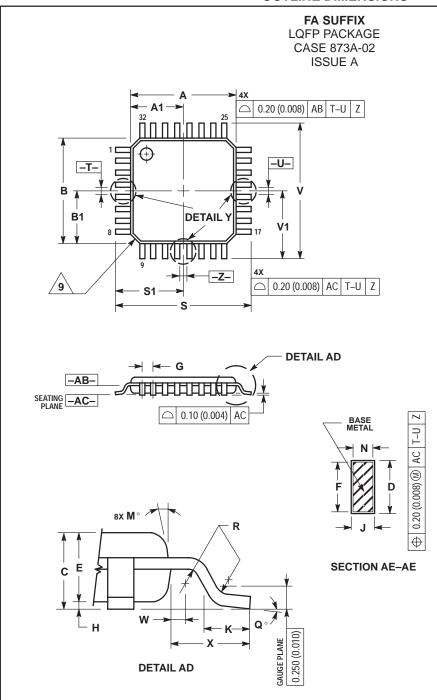
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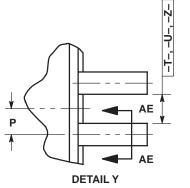
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# **NOTES**

### **OUTLINE DIMENSIONS**





- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DATUM PLANE -AB- IS LOCATED AT BOTTOM
   OF LEAD AND IS COINCIDENT WITH THE LEAD OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING LINE.

  DATUMS -T-, -U-, AND -Z- TO BE DETERMINED AT DATUM PLANE -AB-.

  DIMENSIONS S AND V TO BE DETERMINED AT SEATING PLANE -AC-.

  DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTEINSION ALL QUARDLE PROTEINSION IS

- PROTRUSION. ALLOWABLE PROTRUSION IS 0.250 (0.010) PER SIDE. DIMENSIONS A AND B DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -AB-
- 7. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL NOT CAUSE THE D DIMENSION TO EXCEED 0.520 (0.020).
- MINIMUM SOLDER PLATE THICKNESS SHALL BE
   0.0076 (0.0003).

   EXACT SHAPE OF EACH CORNER MAY VARY

   EXACT SHAPE OF EACH CORNER MAY VARY
- FROM DEPICTION.

	MILLIN	METERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	7.000	7.000 BSC		BSC	
A1	3.500	BSC	0.138 BSC		
В	7.000	BSC	0.276 BSC		
B1	3.500	BSC	0.138	BSC	
С	1.400	1.600	0.055	0.063	
D	0.300	0.450	0.012	0.018	
E	1.350	1.450	0.053	0.057	
F	0.300	0.400	0.012	0.016	
G	0.800	BSC	0.031	BSC	
Н	0.050	0.150	0.002	0.006	
J	0.090	0.200	0.004	0.008	
K	0.500	0.700	0.020	0.028	
M	12°	REF	12°	REF	
N	0.090	0.160	0.004	0.006	
P	0.400 BSC		0.016	BSC	
Q	1∘	5∘	1∘	5°	
R	0.150	0.250	0.006	0.010	
S	9.000	BSC	0.354	BSC	
S1	4.500 BSC 0.177 I		BSC		
V	9.000 BSC		0.354 BSC		
V1	4.500 BSC		0.177 BSC		
W	0.200	REF	0.008	REF	
Х	1.000	REF	0.039	REF	

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